

## **GCE**

# **Electronics**

Unit **F614:** Electronic Control Systems

Advanced GCE

Mark Scheme for June 2014

OCR (Oxford Cambridge and RSA) is a leading UK awarding body, providing a wide range of qualifications to meet the needs of candidates of all ages and abilities. OCR qualifications include AS/A Levels, Diplomas, GCSEs, Cambridge Nationals, Cambridge Technicals, Functional Skills, Key Skills, Entry Level qualifications, NVQs and vocational qualifications in areas such as IT, business, languages, teaching/training, administration and secretarial skills.

It is also responsible for developing new specifications to meet national requirements and the needs of students and teachers. OCR is a not-for-profit organisation; any surplus made is invested back into the establishment to help towards the development of qualifications and support, which keep pace with the changing needs of today's society.

This mark scheme is published as an aid to teachers and students, to indicate the requirements of the examination. It shows the basis on which marks were awarded by examiners. It does not indicate the details of the discussions which took place at an examiners' meeting before marking commenced.

All examiners are instructed that alternative correct answers and unexpected approaches in candidates' scripts must be given marks that fairly reflect the relevant knowledge and skills demonstrated.

Mark schemes should be read in conjunction with the published question papers and the report on the examination.

OCR will not enter into any discussion or correspondence in connection with this mark scheme.

© OCR 2014

### **Quality of Written Communication**

- The candidate expresses complex ideas extremely clearly and fluently. Sentences and paragraphs follow on from one another smoothly and logically. Arguments are consistently relevant and well structured. There will be few, if any, errors of grammar, punctuation and spelling.
- The candidate expresses straightforward ideas clearly, if not always fluently. Sentences and paragraphs may not always be well connected. Arguments may sometimes stray from the point or be weakly presented. There may be some errors of grammar, punctuation and spelling, but not such as to suggest a weakness in these areas.
- The candidate expresses simple ideas clearly, but may be imprecise and awkward in dealing with complex or subtle concepts. Arguments may be of doubtful relevance or obscurely presented. Errors in grammar, punctuation and spelling may be noticeable and intrusive, suggesting weaknesses in these areas.
- The language has no rewardable features.

question	grade	expected answer	mark	additional guidance
1a	Е	2.9 V	1	Allow 2.8 V – 2.9 V
1bi	D	G from switch is -5 V	1	
		S is $0V$ so $VGS = -5V$		
	С	VGS < threshold	1	
	С	so MOSFET not conducting	1	Resistance of MOSFET very high
1bii	Е	line at 0 from t=0 to t=4	1	
	D	oscillation from 4 to end around 0V	1	\4\\ 1
	D	same amplitude, shape and phase as input	1	4 32 1 0 -1 -2 -3 -4 -5

question	grade	expected answer	mark	additional guidance
2a	E	six D-type flip-flops	1	
	Е	5 x Q to next D	1	
	Е	clocks connected together and labelled	1	
	Е	serial in correctly labelled at first D	1	
	Е	outputs correctly labelled at all Qs	1	
2bi	C	first two clock periods correct	1	correct shape but changing on falling edge [2]
	D	periods 3 & 4 correct	1	
	Α	periods 5, 6 correct	1	
		clock		
		z 0 t		
2bii	Α	110001 no ecf	1	beware of reversing order of bits
2biii	С	49 (ecf from bii)	1	-

question	grade	expected answer	mark	additional guidance
3a				n≠m n&m≤7
	Α	go: MOVISn,04	1	
	E	IN Sm,I	1	
	В	AND Sn,Sm	1	OR AND Sm, Sn
	С	JZ go	1	Lose 1 mark if SUB Sm, Sn JNZ go (does not work
	E	RET	1	if X pressed or other I float high)
3b		44		
		4C		
		55		
		5D		
		77		
	C	first one correct	1	
	В	next two correct	1	
	В	last two correct	1	
3c	_	Max 7 of:	7	
	D	Initialise pointer to start of look-up table		
	C	output number from table		Make dice show 1
	Α	move pointer to next item in table		Allow loop 6 times owtte
		check to see if at end of table		
	_	if so reset to start of table		
	D	Mask for X		
	В	check to see if switch is pressed		
	E E	if not go back and output next number from table		
		if pressed return to main program		

question	grade	expected answer	mark	additional guidance
3d	D	make Q7 high	1	0 <j≤7, 0<k≤7,="" j≠k<="" th=""></j≤7,>
	В	without changing Q0-Q6	1	beep: MOVI Sk,80
	С	inititialise counter with C8 (hex for 200)	1	
	С	time delay	1	EOR SO,Sk
	Α	make Q7 low without changing Q0-Q6	1	OUT Q,S0
	E	return	1	
				MOVI Sj,C8
				lbl: RCALL wait1ms
				DEC Sj
				JNZ lbl
				EOR SO,Sk
				OUT Q,S0
				RET

question	grade	expected answer	mark	additional guidance
4a	E E	diodes used to produce rectifier with correct polarity	1	+V unstabilised dc supply  OR  +V unstabilised dc  volume ac supply  ov capacitor used in parallel with output or in 4(c)
4b	CD	Max 2 of: unstabilised has (a large) ripple (wtte) unstabilised output voltage depends on ac input (wtte) regulated output has no/very little ripple (wtte) regulated output fixed/not dependent on input (wtte) regulator keeps the voltage at a constant voltage (wtte)	2	
4c	C	correct reference with zener and resistor connected to op-amp input	1	
	Α	MOSFET used correctly at output	1	
	Α	negative feedback from regulated output	1	

question	grade	expected answer	mark	additional guidance
5a		total R = 22k + 47k		_
	E	I = 6/69000 = 0.087  mA	1	
	Е	0.000087 x 47000 = 4.09 V	1	
5b	С	motor off until G = 1.8 V	1	
	Е	motor speeds up as G increases (from 1.8 V)	1	
	D	as current increases or any reasonable point about what	1	
		happens above 1.8 V		
5c		Max 2:		
	С	speed depends on load (wtte)	1	
	В	no feedback to monitor speed	1	
		speed depends on supply voltage		
		speed depends on MOSFET temp		
5di	CCD	1 mark for each correct label	6	
	DEE			reference difference amplifier generator power amplifier motor
				speed
				sensor
5dii	ABC	Max 3 of:	3	
		output of difference amp non zero		
		output of ramp generator goes up		
		supply to motor increases		

question	grade	expected answer	mark	additional guidance
5e	D C B A	line of constant positive slope from 2 V attempt to use correct ramp generator formula gradient 4 V in 20 ms saturates at +13 V (ecf)	1 1 1 1	V <sub>out</sub> /V 15 10 5
				0 20 40 60 80 100 t/ms
				-15

question	grade	expected answer	mark	additional guidance
6a	DDEE	Max 4 of:	4	1 mark for state, 1 mark for explain
		<ul> <li>subroutines can be re-used</li> </ul>		
		<ul> <li>subroutines can be tested separately</li> </ul>		
		<ul> <li>programs easier to read</li> </ul>		
		<ul> <li>programs easier to write due to structure</li> </ul>		
		<ul> <li>saves memory because subroutine only needs to</li> </ul>		
		be stored once		
6b	С	value retrieved from stack	1	
	С	and stored in program counter to instruction after RCALL	1	
	Α	stack pointer changed by 1	1	
6c	A*	instructions unchanged	1	
	A*	program counter = 2E	1	
	A*	stack pointer changed by 1 (56 or 58)	1	
	A*	all but one data value unchanged	1	
	A*	one data value now 2C (address 56, 57 or 58)	1	Allow 2D

question	grade	expected answer	mark	additional guidance
7a	E	input connected to V <sub>G</sub>	1	18 V
	E E	output connected to V <sub>D</sub>	1	Д
	Е	each input connected through a capacitor	1	200Ω
				20052
				R output
				input - , II
				V <sub>G</sub>
				₩ <sub>G</sub> H
				h
				470kΩ
				니 니
				0V-
7bi	Α	from graph $g_m = 0.05 S$	1	transconductance calculated
	В	$R = 200 \Omega$	1	$200~\Omega$ used
	Α	gain = $-0.05 \times 200 = -10 \text{ (ecf g}_m)$	1	gain -ve
7bii	A*	V across 200Ω: 18 – 10 = 8 V	1	
	A*	I = 8 / 200 = 0.04 A	1	
	A*	from graph $V_G = 2.3 \text{ V}$	1	
	A*	I in 470 kΩ: 2.3/470000 = 4.89 μA	1	
	A*	V across R: 10 – 2.3 = 7.7 V (ecf from 8bii)	1	
	A*	$R = 7.7 / 4.89 \times 10^{-6} = 1600 \text{ k}\Omega$	1	
7c	A*	MOSFETs have different characteristics	1	
	A*	Affects bias	1	
		design not so sensitive to different MOSFETs		

question	grade	expected answer			m	ark	additional guidance
8ai			•				1 mark for each correct row
		Q	U	L			
	Е	0	open	closed		1	
	Е	1	closed	open		1	
	Е	High impedance	open	open		1	
8aii	D D D	logic to turn off bot logic turns off both logic turns reprodu E)	h analogue switches analogue switches	es with E s when E high		1 1 1	E.g. 5 V
							E OV
Ob	_	4				4	or any other working logic
8b	D E	to disconnect the c	output from the bus	anactad to the sam		1 1	
		so that more than i	nemory can be con	medied to the Sam	<sup>E</sup>	1	
8c	E	tristates between o	on each ∩			1	
00	E	2Qs to each Data I				1	
	E	2Ds to each data li				1	
	D	Read operates tris				1	
	D	write operates cloc				1	
	В	A0 routes read and				1	
	Ь	The routes read and	write correctly			I	

question	grade	expected answer	mark	additional guidance
8d	Е	information lost when power is turned off	1	

**OCR (Oxford Cambridge and RSA Examinations)** 1 Hills Road Cambridge **CB1 2EU** 

#### **OCR Customer Contact Centre**

## **Education and Learning**

Telephone: 01223 553998 Facsimile: 01223 552627

Email: general.qualifications@ocr.org.uk

#### www.ocr.org.uk

For staff training purposes and as part of our quality assurance programme your call may be recorded or monitored

Oxford Cambridge and RSA Examinations is a Company Limited by Guarantee Registered in England Registered Office; 1 Hills Road, Cambridge, CB1 2EU Registered Company Number: 3484466 **OCR** is an exempt Charity

**OCR (Oxford Cambridge and RSA Examinations)** Head office

Telephone: 01223 552552 Facsimile: 01223 552553



